Not Recommended for New Design Alternative is BCP54 & BCP5416



DCP54/-16

NPN SURFACE MOUNT TRANSISTOR

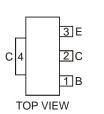
Features

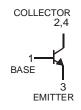
- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DCP51)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.115 grams (approximate)







Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	45	V
Collector-Base Voltage	V_{CBO}	45	V
Emitter-Base Voltage	V_{EBO}	5	V
Continuous Collector Current	Ic	1	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @T _A = 25°C	P_d	1	W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C
Thermal Resistance Junction to Ambient Air @ T _A = 25°C (Note 3)	$R_{ heta JA}$	125	°C/W

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Off Characteristics (Note 4)							
Collector-Base Breakdown Voltage		V _{(BR)CBO}	45			V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage		V _{(BR)CEO}	45	_	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage		V _{(BR)EBO}	5			V	$I_E = 10\mu A$
Collector-Base Cutoff Current		I _{CBO}	_	_	100	nA	$V_{CB} = 30V, I_{E} = 0$
					10	μΑ	$V_{CB} = 30V, I_E = 0, T_A = 150^{\circ}C$
Emitter-Base Cutoff Current		I _{EBO}	_		10	μΑ	$V_{EB} = 5V$, $I_C = 0A$
On Characteristics (Note 4)							
			63		_		$I_C = 5mA$, $V_{CE} = 2V$
DC Current Gain		h _{FE}	63	_	250		$I_C = 150 \text{mA}, V_{CE} = 2V$
DC Current Gain			40		_	_	$I_C = 500 \text{mA}, V_{CE} = 2V$
	DCP54-16		100		250		$I_C = 150 \text{mA}, V_{CE} = 2V$
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	_		500	mV	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Voltage		V _{BE(ON)}	_		1	V	I _C = 500mA, V _{CE} = 2V
Small Signal Characteristics							
Transition Frequency		f _T	_	200		MHz	$I_C = 50 \text{mA}, V_{CE} = 5 \text{V}, f = 100 \text{MHz}$

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB, pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 4. Measured under pulsed conditions. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$



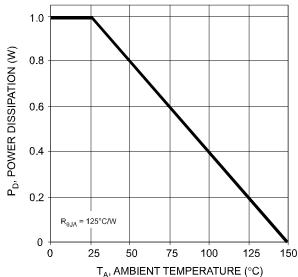


Fig. 1 Power Dissipation vs. Ambient Temperature

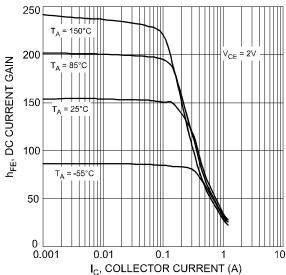


Fig. 3 Typical DC Current Gain vs. Collector Current

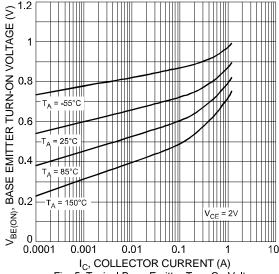
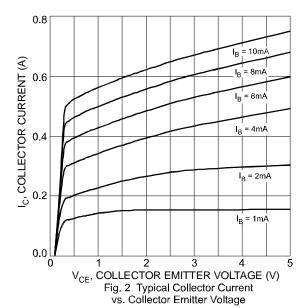


Fig. 5 Typical Base Emitter Turn-On Voltage vs. Collector Current



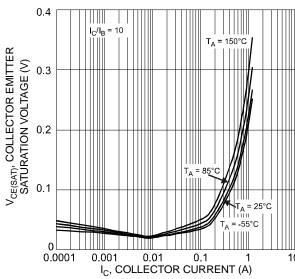


Fig. 4 Typical Collector Emitter Saturation Voltage vs. Collector Current

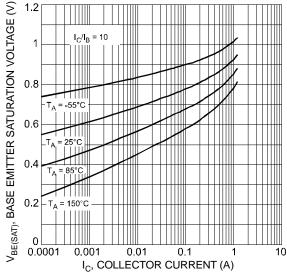
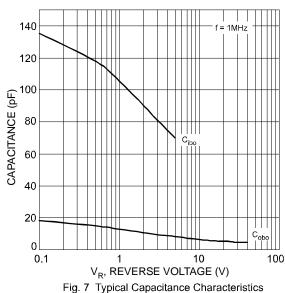
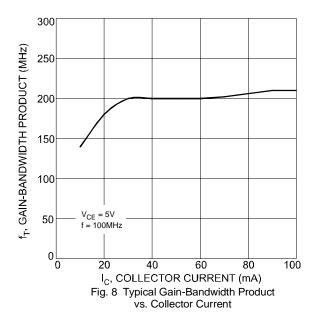


Fig. 6 Typical Base Emitter Saturation Voltage vs. Collector Current



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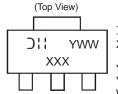
N14 = DCP54 N14-16 = DCP54-16

Ordering Information (Note 5)

Device	Packaging	Shipping
DCP54-13	SOT-223	2500/Tape & Reel
DCP54-16-13	SOT-223	2500/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/ap02007.pdf.

Marking Information

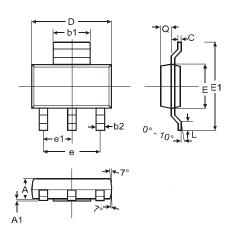


Oll = Manufacturer's code marking

XXX = Product type marking code Ex:

YWW = Date code marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

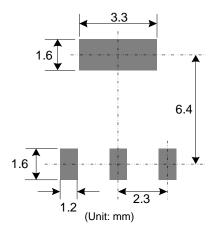
Package Outline Dimensions



SOT-223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					



Suggested Pad Layout: (Based on IPC-SM-782)



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